### **USHIO Exposure System "UX Series"**

USHIO INC., celebrating its 50-year anniversary, has been serving the global semiconductor industry as a leading supplier of UV lamps for photolithography processes, VUV lamps for surface improvement, and halogen lamps for thermal processes. Today, USHIO have developed, manufactured, and marketed a wide range of lithography tools "UX Series" for advanced packaging (fine-printed circuit boards) and wafer-level packaging (WLP), as well as MEMS, LEDs, and power devices.

The UX Series provides line up the three major types of exposure systems: full-field progection, proximity, and contact, while i supporting a wide range of substrates including silicon wafers, P boards, and roll-to-roll films. The UX Series is a best collection of USHIO's original elemental technologies: light sources, optics including lens and mirrors, mask/substrate transfer, and alignment mechanisms. Today, more than 1,300 units of USHIO lithography tools are operating worldwide.

## **USHIO's Major "UX Series" Products and Packaging Applications**



# "UX4 Series" Large-Area, Full-Field Projection Lithography Systems

Optimum for Various Advanced Applications, including MEMS Devices, High-Brightness LEDs, and Power Devices.

USHIO provides the "UX4 Series" of full-field projection exposure lithography tools to manufacture MEMS devices, high-brightness LEDsand power devices. Use of the mask-damage-free projection exposure method as well as the capability of full-field exposure of a wafer of up to 200 mm in diameter allows great enhancement of the productivity of and significant reduction for manufacturing the above products.

"UX4 Series" Large-Area Full-Field Projection Lithography Systems		
Model	Application	Wafer Size
UX4-MEMS	MEMS devices	
UX4-LEDs	High-brightness LEDs	Max. 200 mm
UX4-ECO	Power devices	



UX4 Large-Area, Full-Field Projection Lithography System

#### **UX-4 Series Features**

- Automated transfer of wafers up to 200 mm in diameter
- Completely non-contact so as to cause no mask damage; thus, no mask cleaning, inspection, or replacement is required
- Proprietary alignment technology that enables easy detection of low-visibility alignment marks
- Large depth of focus of 500 μm or less and special wafer chucking method allows high-precision exposure of warped or stepped substrates or thick photoresist
- Allows simultaneous projection of both sides of a wafer to enhance productivity
- Modular design of each function on a common platform allows easy future upgrades

### **UX-4 Series Specifications by Models**

Resolution:	2 μm L/S~	
Wavelength:	365 nm	
Overlay Accuracy:	±1μm (Top Side), ±1.5 μm (Back Side)	
Throughput:	120 wph	
Wafer Size:	∅100 mm/150 mm/200 mm	
Substrates:	Si, Sapphire, GaN, GaAs, SiC, and glass	
Substrate Transfer Method	Automated wafer transfer on the UX4 Series platform	

Note: The specifications may slightly vary depending on applications.



Mounting Full-Field Projection Lens Originally Developed by USHIO

# **USHIO** Welcomes Demonstration Requests and Inquiries about Its **UX** Series **Products**

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